

NPN SILICON PLANAR EPITAXIAL TRANSISTOR

CD13001





ABSOLUTE MAXIMUM RATING (T_a =25°C)

DESCRIPTION	SYMBOL	VALUE	UNIT
Collector Base Voltage	V _{CBO}	500	V
Collector Emitter Voltage	V _{CEO}	400	V
Emitter Base Voltage	V _{EBO}	9.0	V
Collector Current Continuous	Ι _C	0.5	А
Peak (1)	I _{CM}	1.5	
Collector Power Dissipation	P _C	900	mW
Operating and Storage Junction	T _j , T _{stg}	- 55 to +150	°C
Temperature Range		7 St	
(1) Pulse Test: Pulse Width = 5ms,	Duty Cycle <u><</u>	10%	
ELECTRICAL CHARACTERISTICS	(T_=25°C unle	ess specified otherwise)	

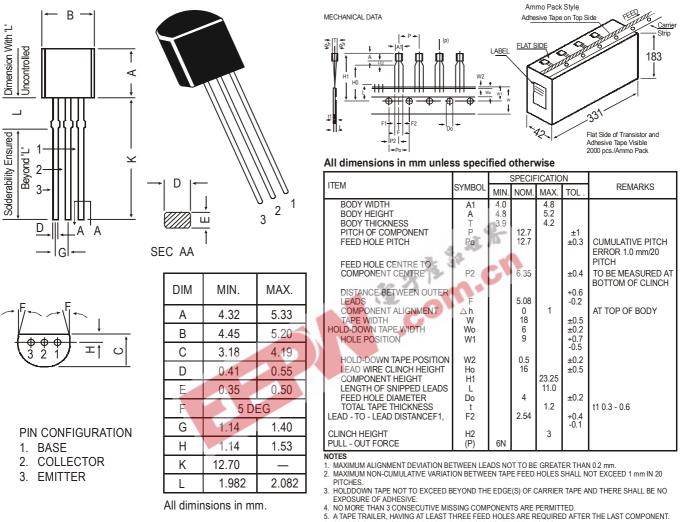
ELECTRICAL CHARACTERISTICS (T_a=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Collector Base Voltage		I _C =100μA, I _E =0	500			V
Collector Emitter Voltage	V _{CEO}	I _C =1mA, I _B =0	400			V
Emitter Base Voltage	V _{EBO}	I _E =100μΑ, I _C =0	9			V
Collector Cut off Current	Ісво	V _{CB} =500V, I _E = 0			100	μA
	ICEO	V _{CE} =400V, I _B = 0			200	
Emitter Cut off Current	I _{EBO}	V _{EB} =9V, I _C =0			100	μA
DC Current Gain	h _{FE} *	V _{CE} =20V, I _C =20mA	10		40	
	h _{FE}	V _{CE} =10V, I _C =0.25mA	5			
Collector Emitter Saturation	V _{CE(sat)}	I _C =50mA, I _B =10mA			0.5	V
Voltage						
Base Emitter Saturation Voltage	V _{BE(sat)}	I _C =50mA, I _B =10mA			1.2	V
Transition Frequency f _T		V _{CE} =20V,I _C =20mA,f=1MHz	8			MHz
Fall Time	II Time t _f				0.3	μs
Storage Time		V _{CC} =45V			1.5	

h _{FE} Classifications						
Note: Product is pre selected in	Α	В	С	D	E	F
DC current gain (Groups A to F). CDIL reserves the right to ship any of the groups according to production availability.	10-15	15-20	20-25	25-30	30-35	35-40
MARKING	CD 13001 A	CD 13001 B	CD 13001 C	CD 13001 D	CD 13001 E	CD 13001 F

TO-92 Plastic Package

TO-92 Plastic Package



TO-92 Transistors on Tape and Ammo Pack

5. 6. SPLICES SHALL NOT INTERFERE WITH THE SPROCKET FEED HOLES.

Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-92 Bulk TO-92 T&A	1K/polybag 2K/ammo box	200 gm/1K pcs 645 gm/2K pcs	3" x 7.5" x 7.5" 12.5" x 8" x 1.8"	5K 2K	17" x 15" x 13.5" 17" x 15" x 13.5"	80K 32K	23 kgs 12.5 kgs

TO-92 Plastic Package



Disclaimer

The product information and the selection guides facilitate selection of the CDIL's Discrete Semiconductor Device(s) best suited for application in your product(s) as per your requirement. It is recommended that you completely review our Data Sheet(s) so as to confirm that the Device(s) meet functionality parameters for your application. The information furnished in the Data Sheet and on the CDIL Web Site/CD is believed to be accurate and reliable. CDIL however, does not assume responsibility for inaccuracies or incomplete information. Furthermore, CDIL does not assume liability whatsoever, arising out of the application or use of any CDIL product; neither does it convey any license under its patent rights nor rights of others. These products are not designed for use in life saving/support appliances or systems. CDIL customers selling these products (either as individual Discrete Semiconductor Devices or incorporated in their end products), in any life saving/support appliances or systems or applications do so at their own risk and CDIL will not be responsible for any damages resulting from such sale(s).

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Continental Device India Limited

C-120 Naraina Industrial Area, New Delhi 110 028, India. Telephone + 91-11-579 6150 Fax + 91-11-579 9569, 579 5290 e-mail sales@cdil.com www.cdil.com

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